### **Accepted Manuscript**

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DHYSICA LONGINGSOMA SYSTIMS

IN MINISTRACIONS

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PII: \$1386-9477(17)31596-5

DOI: 10.1016/j.physe.2018.01.028

Reference: PHYSE 13037

To appear in: Physica E: Low-dimensional Systems and Nanostructures

Received Date: 16 October 2017
Revised Date: 23 January 2018
Accepted Date: 26 January 2018

Please cite this article as: Y. Wang, Y. Chen, X. Song, Z. Zhang, J. She, S. Deng, N. Xu, J. Chen, Electrical properties of fluorine-doped ZnO nanowires formed by biased plasma treatment, *Physica E: Low-dimensional Systems and Nanostructures* (2018), doi: 10.1016/j.physe.2018.01.028.

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#### ACCEPTED MANUSCRIPT

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Ying Wang, Yicong Chen, Xiaomeng Song, Zhipeng Zhang, Juncong She, Shaozhi

Deng, Ningsheng Xu, Jun Chen\*

State Key Laboratory of Optoelectronic Materials and Technologies, Guangdong Province Key Laboratory of Display Material and Technology, and School of Electronics and Information Technology, Sun Yat-sen University, Guangzhou 510275, People's Republic of China

\* E-mail: stscjun@mail.sysu.edu.cn

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